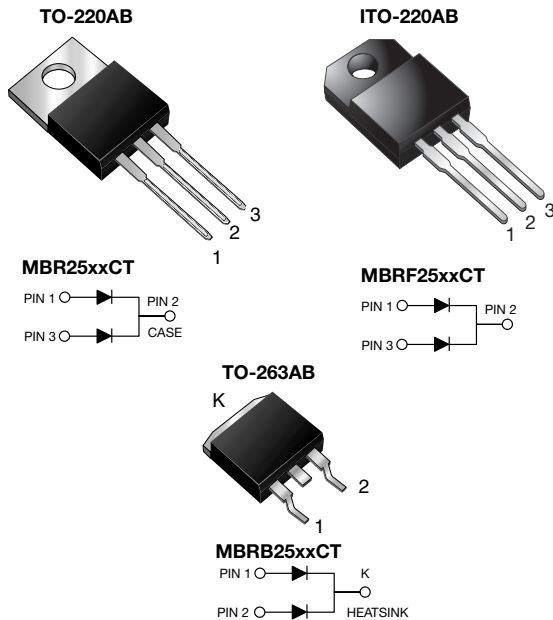


## Dual Common-Cathode Schottky Rectifier



### FEATURES

- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 260 °C, 40 s (for TO-220AB and ITO-220AB package)
- Compliant to RoHS 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB  
Epoxy meets UL 94 V-0 flammability rating

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC-Q101 qualified), meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

| PRIMARY CHARACTERISTICS |                                |
|-------------------------|--------------------------------|
| $I_{F(AV)}$             | 2 x 12.5 A                     |
| $V_{RRM}$               | 35 V to 60 V                   |
| $I_{FSM}$               | 150 A                          |
| $V_F$                   | 0.73 V at 30 A, 0.65 V at 15 A |
| $T_J$ max.              | 150 °C                         |

| MAXIMUM RATINGS ( $T_C = 25\text{ °C}$ unless otherwise noted)                               |                                          |           |           |           |           |                  |
|----------------------------------------------------------------------------------------------|------------------------------------------|-----------|-----------|-----------|-----------|------------------|
| PARAMETER                                                                                    | SYMBOL                                   | MBR2535CT | MBR2545CT | MBR2550CT | MBR2560CT | UNIT             |
| Maximum repetitive peak reverse voltage                                                      | $V_{RRM}$                                | 35        | 45        | 50        | 60        | V                |
| Working peak reverse voltage                                                                 | $V_{RWM}$                                | 35        | 45        | 50        | 60        |                  |
| Maximum DC blocking voltage                                                                  | $V_{DC}$                                 | 35        | 45        | 50        | 60        |                  |
| Maximum average forward rectified current<br>at $T_C = 130\text{ °C}$                        | total device<br>$I_{F(AV)}$<br>per diode | 25        |           |           |           | A                |
|                                                                                              |                                          | 12.5      |           |           |           |                  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | $I_{FSM}$                                | 150       |           |           |           | A                |
| Peak repetitive reverse surge current per diode at $t_p = 2\text{ }\mu\text{s}$ , 1 kHz      | $I_{RRM}$                                | 1.0       |           | 0.5       |           |                  |
| Peak non-repetitive reverse energy (8/20 $\mu\text{s}$ waveform) per diode                   | $E_{RSM}$                                | 25        |           |           |           | mJ               |
| Electrostatic discharge capacitor voltage human body model: C = 100 pF, R = 1.5 k $\Omega$   | $V_C$                                    | 25        |           |           |           | kV               |
| Voltage rate of change (rated $V_R$ )                                                        | dV/dt                                    | 10 000    |           |           |           | V/ $\mu\text{s}$ |

# MBR(F,B)2535CT thru MBR(F,B)2560CT

Vishay General Semiconductor



| MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)           |                  |               |           |           |           |      |
|---------------------------------------------------------------------------|------------------|---------------|-----------|-----------|-----------|------|
| PARAMETER                                                                 | SYMBOL           | MBR2535CT     | MBR2545CT | MBR2550CT | MBR2560CT | UNIT |
| Operating junction temperature range                                      | T <sub>J</sub>   | - 65 to + 150 |           |           |           | °C   |
| Storage temperature range                                                 | T <sub>STG</sub> | - 65 to + 175 |           |           |           |      |
| Isolation voltage (ITO-220AB only)<br>from terminal to heatsink t = 1 min | V <sub>AC</sub>  | 1500          |           |           |           | V    |

| ELECTRICAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |                         |                         |                               |           |           |           |           |      |
|----------------------------------------------------------------------------|-------------------------|-------------------------|-------------------------------|-----------|-----------|-----------|-----------|------|
| PARAMETER                                                                  | TEST CONDITIONS         |                         | SYMBOL                        | MBR2535CT | MBR2545CT | MBR2550CT | MBR2560CT | UNIT |
| Maximum instantaneous forward voltage per diode                            | I <sub>F</sub> = 15 A   | T <sub>C</sub> = 25 °C  | V <sub>F</sub> <sup>(1)</sup> | -         | -         | 0.75      |           | V    |
|                                                                            |                         | T <sub>C</sub> = 125 °C |                               | -         | -         | 0.65      |           |      |
|                                                                            | I <sub>F</sub> = 30 A   | T <sub>C</sub> = 25 °C  |                               | 0.82      | -         | -         |           |      |
|                                                                            |                         | T <sub>C</sub> = 125 °C |                               | 0.73      | -         | -         |           |      |
| Maximum instantaneous reverse current at blocking voltage per diode        | T <sub>C</sub> = 25 °C  |                         | I <sub>R</sub> <sup>(1)</sup> | 0.2       | -         | 1.0       |           | mA   |
|                                                                            | T <sub>C</sub> = 125 °C |                         |                               | 40        | -         | 50        |           |      |

**Note**

<sup>(1)</sup> Pulse test: 300 μs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |                  |     |      |      |      |  |
|-------------------------------------------------------------------------|------------------|-----|------|------|------|--|
| PARAMETER                                                               | SYMBOL           | MBR | MBRF | MBRB | UNIT |  |
| Typical thermal resistance from junction to case per diode              | R <sub>θJC</sub> | 1.5 | 4.5  | 1.5  | °C/W |  |

| ORDERING INFORMATION (Example) |                                 |                 |              |               |               |  |
|--------------------------------|---------------------------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE                        | PREFERRED P/N                   | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |
| TO-220AB                       | MBR2545CT-E3/45                 | 1.85            | 45           | 50/tube       | Tube          |  |
| ITO-220AB                      | MBRF2545CT-E3/45                | 1.99            | 45           | 50/tube       | Tube          |  |
| TO-263AB                       | MBRB2545CT-E3/45                | 1.35            | 45           | 50/tube       | Tube          |  |
| TO-263AB                       | MBRB2545CT-E3/81                | 1.35            | 81           | 800/reel      | Tape and reel |  |
| TO-220AB                       | MBR2545CT-E3/4W                 | 1.85            | 4W           | 50/tube       | Tube          |  |
| TO-220AB                       | MBR2545CTHE3/45 <sup>(1)</sup>  | 1.85            | 45           | 50/tube       | Tube          |  |
| ITO-220AB                      | MBRF2545CTHE3/45 <sup>(1)</sup> | 1.99            | 45           | 50/tube       | Tube          |  |
| TO-263AB                       | MBRB2545CTHE3/45 <sup>(1)</sup> | 1.35            | 45           | 50/tube       | Tube          |  |
| TO-263AB                       | MBRB2545CTHE3/81 <sup>(1)</sup> | 1.35            | 81           | 800/reel      | Tape and reel |  |

**Note**

<sup>(1)</sup> AEC-Q101 qualified

## RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

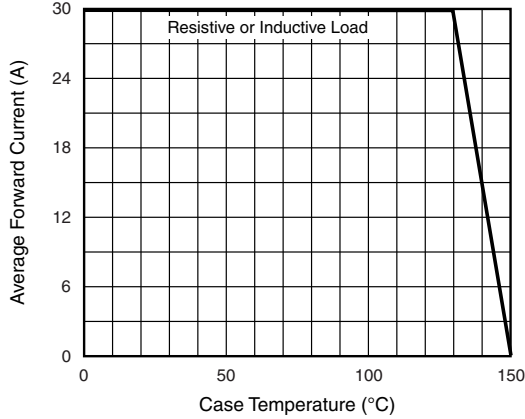


Fig. 1 - Forward Current Derating Curve

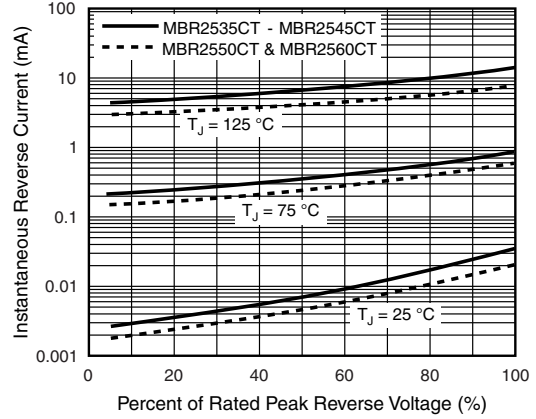


Fig. 4 - Typical Reverse Characteristics Per Diode

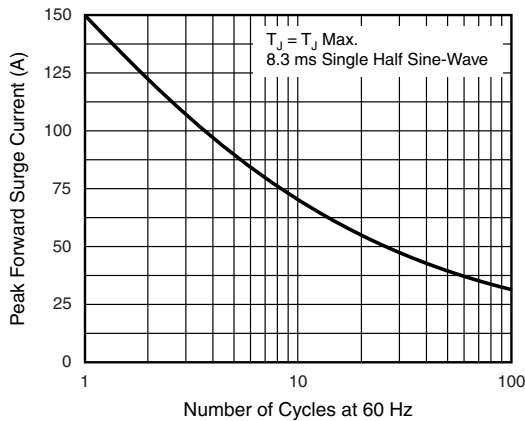


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

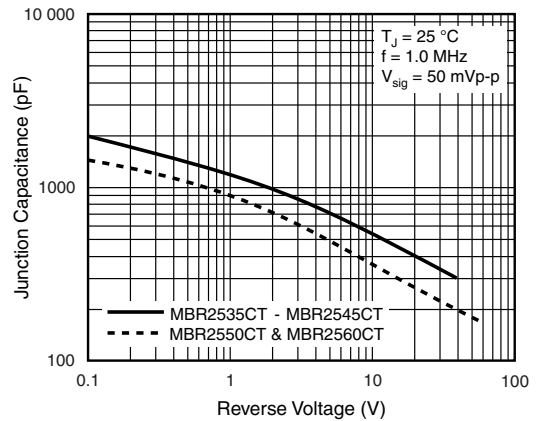


Fig. 5 - Typical Junction Capacitance Per Diode

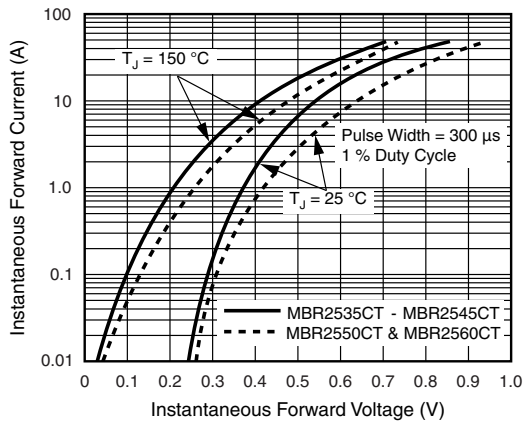


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

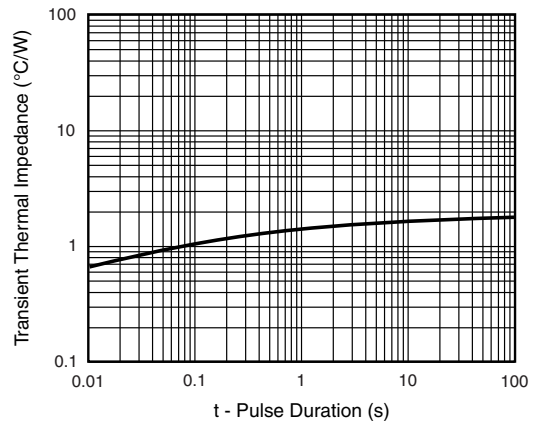


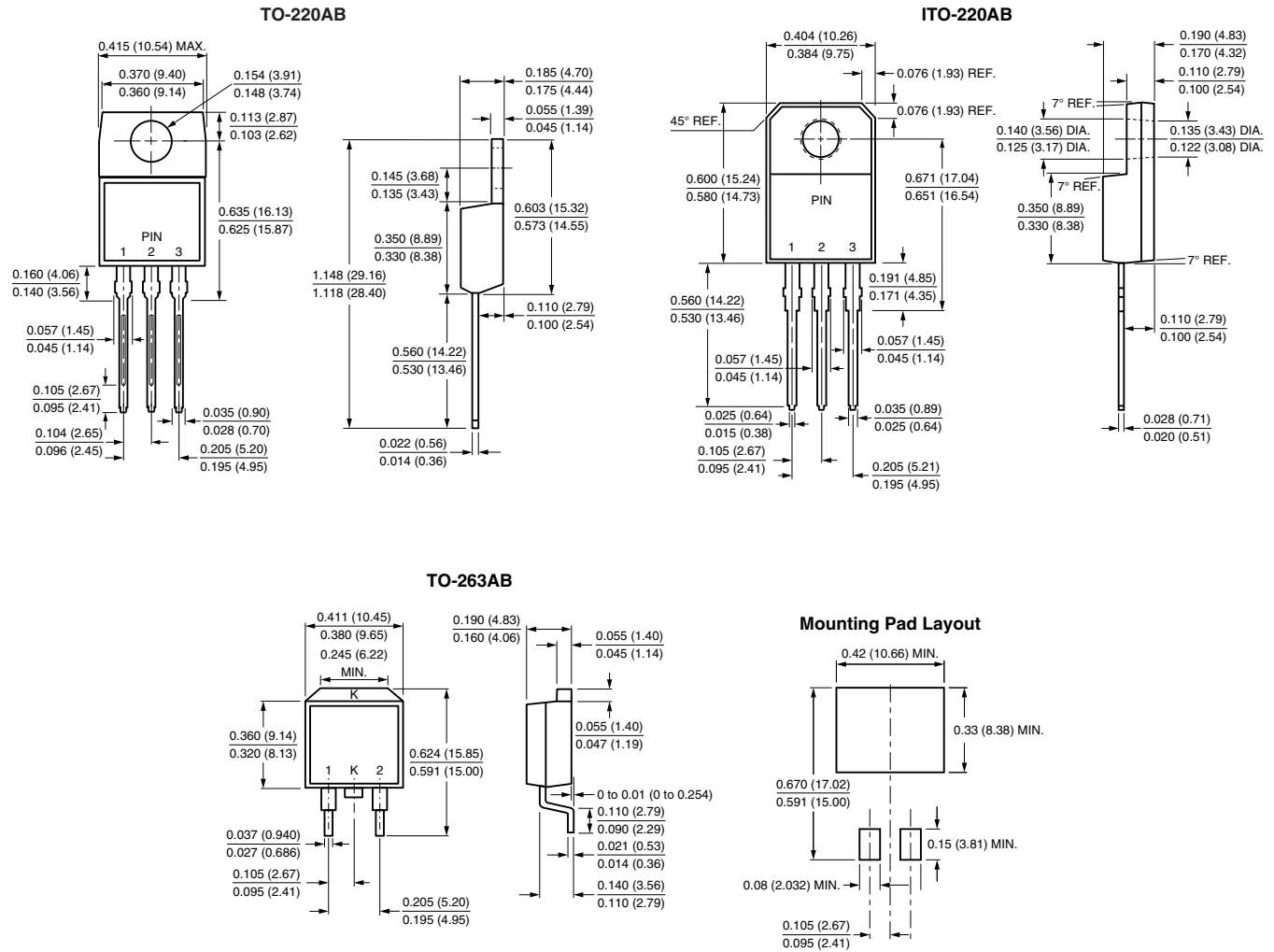
Fig. 6 - Typical Transient Thermal Impedance Per Diode

# MBR(F,B)2535CT thru MBR(F,B)2560CT

Vishay General Semiconductor



## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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